

Vishay High Power Products

Medium Power

Silicon Rectifier Diodes, 12 A



DO-203AA (DO-4)

Range

12 A

FEATURES

• Voltage ratings from 50 to 1000 V



- · High surge capability
- · Low thermal impedance
- · High temperature rating

- 65 to 200

50 to 1000 (1)

· Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260

°С

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· RoHS compliant

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{F(AV)}		12 ⁽¹⁾	A		
	T _C	150 ⁽¹⁾	°C		
I _{FSM}	50 Hz	230	^		
	60 Hz	240 (1)			
l²t	50 Hz	Hz 260			
	60 Hz	240	- A ² s		

 T_C

 V_{RRM}

PRODUCT SUMMARY

 $I_{F(AV)}$

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER (2)	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{R(RMS)} , MAXIMUM RMS REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE V	
	T _C = - 65 °C TO 200 °C	T _C = - 65 °C TO 200 °C	T _C = - 65 °C TO 200 °C	T _C = - 65 °C TO 200 °C	
1N1199A	50 (1)	35 (1)	100 (1)	50 (1)	
1N1200A	100 (1)	70 (1)	200 (1)	100 (1)	
1N1201A	150 ⁽¹⁾	105 ⁽¹⁾	300 (1)	150 ⁽¹⁾	
1N1202A	200 (1)	140 (1)	350 (1)	200 (1)	
1N1203A	300 (1)	210 (1)	450 ⁽¹⁾	300 (1)	
1N1204A	400 (1)	280 (1)	600 (1)	400 (1)	
1N1205A	500 (1)	350 (1)	700 (1)	500 (1)	
1N1206A	600 (1)	420 (1)	800 (1)	600 (1)	
1N3670A	700 (1)	490	900 (1)	700 (1)	
1N3671A	800 (1)	560	1000 (1)	800 (1)	
1N3672A	900 (1)	630	1100 (1)	900 (1)	
1N3673A	1000 (1)	700	1200 (1)	1000 (1)	

Notes

⁽¹⁾ JEDEC registered values

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⁽²⁾ Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

1N1...A, 1N36..A Series

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FORWARD CO	NDUCTION	1				
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current		I	180° sinusoidal conduction		12 (1)	А
at case temperature		I _{F(AV)}	100 Siliusoidal colluction	nusoidal conduction		°C
Maximum peak one cycle non-repetitive surge current		I _{FSM}	Half cycle 50 Hz sine wave	Following any rated load condition and with rated V _{RRM} applied	230	
			or 6 ms rectangular pulse Half cycle 60 Hz sine wave			
			or 5 ms rectangular pulse		240 (1)	
			Half cycle 50 Hz sine wave	Following any rated load condition and with V _{RRM} applied following surge = 0	275	A A
			or 6 ms rectangular pulse			
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		285	
Maximum I ² t for fusing			t = 10 ms	With rated V _{RRM} applied following surge, initial T _J = 200 °C	260	A ² s
		l ² t	t = 8.3 ms		240	
Maximum I ² t for indivi	Maximum I ² t for individual		t = 10 ms	With V _{RRM} = 0 following surge, initial T _J = 200 °C	370	
device fusing			t = 8.3 ms		340	
Maximum I ² √t for individual device fusing		I ² √t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		3715	A²√s
Maximum forward voltage drop		V _{FM}	I _{F(AV)} = 12 A (38 A peak), T _C = 25 °C		1.35 (1)	V
	V _{RRM} = 50		Maximum rated I _{F(AV)} and T _C		3.0 (1)	mA
	V _{RRM} = 100				2.5 (1)	
	V _{RRM} = 150				2.25 (1)	
	V _{RRM} = 200				2.0 (1)	
	V _{RRM} = 300	I _{B(AV)} (3)			1.75 ⁽¹⁾	
Maximum average reverse current	V _{RRM} = 400				1.5 (1)	
	V _{RRM} = 500				1.25 (1)	
	V _{RRM} = 600				1.0 (1)	
	V _{RRM} = 700				0.9 (1)	
	V _{RRM} = 800				0.8 (1)	
	V _{RRM} = 900				0.7 (1)	
	V _{RRM} = 1000				0.6 (1)	

Notes

- (1) JEDEC registered values
- (2) I²t for time $t_x = I^2 \sqrt{t} \times \sqrt{t_x}$
- $^{(3)}$ Maximum peak reverse current (I_{RM}) under same conditions $\approx 2~x$ rated I_{R(AV)}





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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating case and storage temperature range		T _C , T _{Stg}		- 65 to 200 ⁽¹⁾	°C	
Maximum internal thermal resistance, junction to case		R _{thJC}	DC operation	2.0 (1)	0044	
Thermal resistance, case to sink		R _{thCS}	Mounting surface, smooth, flat and greased	0.5	°C/W	
Mounting torque	minimum		Torque applied to nut; non-lubricated threads	1.36 (12)	N ⋅ m (lbf ⋅ in)	
	maximum			1.69 (15)		
	minimum		Torque applied to nut; lubricated threads	1.07 (9.45)		
	maximum		Torque applied to flut, lubricated threads	1.30 (11.55)		
	minimum		Torque applied to device case; lubricated threads	1.17 (10.35)		
	maximum			1.43 (12.65)		
Approximate weight				7.0	g	
				0.25	OZ.	
Case style			JEDEC	DO-203A	A (DO-4)	

Note

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⁽¹⁾ JEDEC registered values

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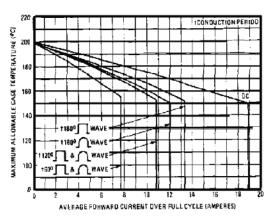
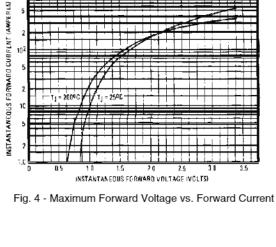


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature



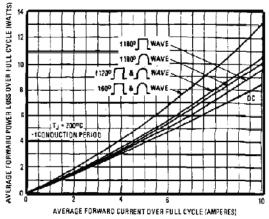


Fig. 2 - Maximum Low Level Forward Power Loss vs. Average Forward Current

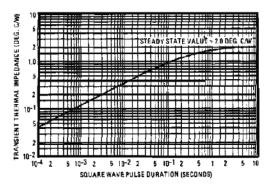


Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration

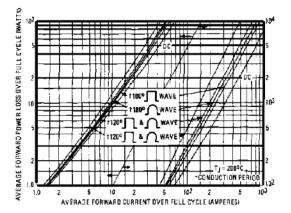


Fig. 3 - Maximum High Level Forward Power Loss vs. Average Forward Current

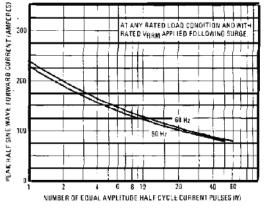


Fig. 6 - Maximum Non-Repetitive 50 Hz Surge Current vs. Number of Current Pulses

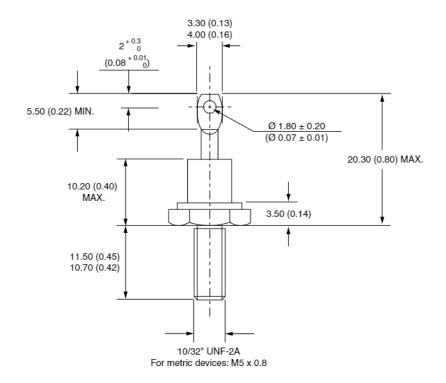
LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95311		

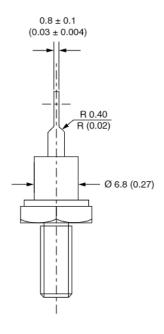


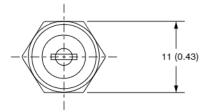
Vishay Semiconductors

DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)









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